

ACNW3190

5.0 Amp High Output Current IGBT Gate Drive Optocoupler



Data Sheet



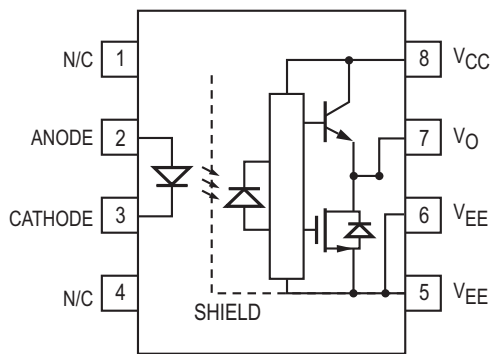
Lead (Pb) Free
RoHS 6 fully compliant

RoHS 6 fully compliant options available;
-xxxE denotes a lead-free product

Description

The ACNW3190 contains an AlGaAs LED, which is optically coupled to an integrated circuit with a power output stage. This optocoupler is ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications. The high operating voltage range of the output stage provides the drive voltages required by gate controlled devices. The voltage and high peak output current supplied by this optocoupler make it ideally suited for direct driving IGBTs with ratings up to 1200V/200 A, 600 V/300 A. For IGBTs with higher ratings, the ACNW3190 can be used to drive a discrete power stage which drives the IGBT gate. The ACNW3190 has the highest insulation voltage of $V_{IORM}=1414 V_{peak}$ in the IEC/ EN/DIN EN 60747-5-5.

Functional Diagram



TRUTH TABLE

| LED | $V_{CC} - V_{EE}$ "POSITIVE GOING" (i.e., TURN-ON) | $V_{CC} - V_{EE}$ "NEGATIVE GOING" (i.e., TURN-OFF) | V_O |
|-----|--|---|------------|
| OFF | 0 - 30 V | 0 - 30 V | LOW |
| ON | 0 - 11 V | 0 - 9.5 V | LOW |
| ON | 11 - 13.5 V | 9.5 - 12 V | TRANSITION |
| ON | 13.5 - 30 V | 12 - 30 V | HIGH |

A 0.1 μ F bypass capacitor must be connected between pins 5 and 8.

Features

- 5.0 A Maximum Peak Output Current
- 15 kV/ μ s Minimum Common Mode Rejection (CMR) at $V_{CM} = 1500$ V
- 0.5 V Maximum Low Level Output Voltage (V_{OL}) Eliminates Need for Negative Gate Drive
- $I_{CC} = 5$ mA Maximum Supply Current
- Under Voltage Lock-Out Protection (UVLO) with Hysteresis
- Wide Operating V_{CC} Range: 15 to 30 Volts
- 500 ns Maximum Switching Speeds
- Industrial Temperature Range: -40°C to 100°C
- Safety Approval

UL Recognized

5000 V_{rms} for 1 min.

CSA Approval

IEC/EN/DIN EN 60747-5-5 Approved

$V_{IORM} = 1414 V_{peak}$

Applications

- IGBT/MOSFET Gate Drive
- AC/Brushless DC Motor Drives
- Industrial Inverters
- Switch Mode Power Supplies

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

Ordering Information

ACNW3190 is UL Recognized with 5000Vrms for 1 minute per UL1577.

| Part number | Option | | Surface Mount | Gull Wing | Tape & Reel | IEC/EN/DIN EN 60747-5-5 | Quantity |
|-------------|----------------|-----------------|---------------|-----------|-------------|-------------------------|--------------|
| | RoHS Compliant | Package | | | | | |
| ACNW3190 | -000E | 400mil DIP-8 | | | | X | 42 per tube |
| | -300E | | X | X | | X | 42 per tube |
| | -500E | | X | X | X | X | 750 per reel |

To order, choose a part number from the part number column and combine with the desired option from the option column to form an order entry.

Example 1:

ACNW3190-500E to order product of 400mil DIP Gull Wing Surface Mount package in Tape and Reel packaging with IEC/EN/DIN EN 60747-5-5 Safety Approval in RoHS compliant.

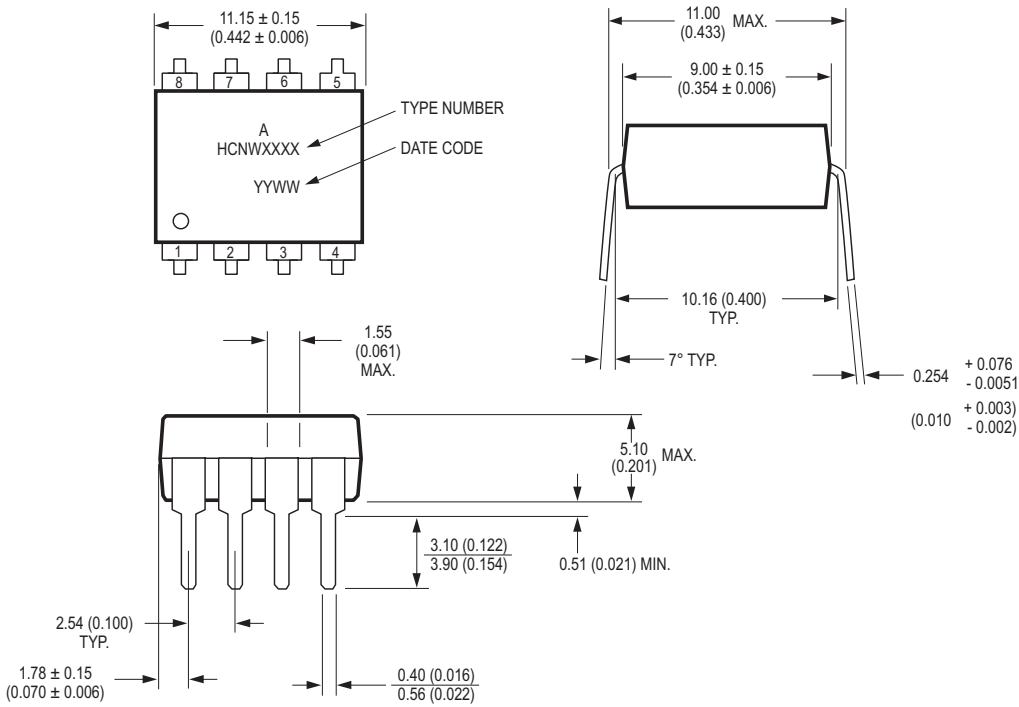
Example 2:

ACNW3190-000E to order product of 400mil DIP package in tube packaging and RoHS compliant.

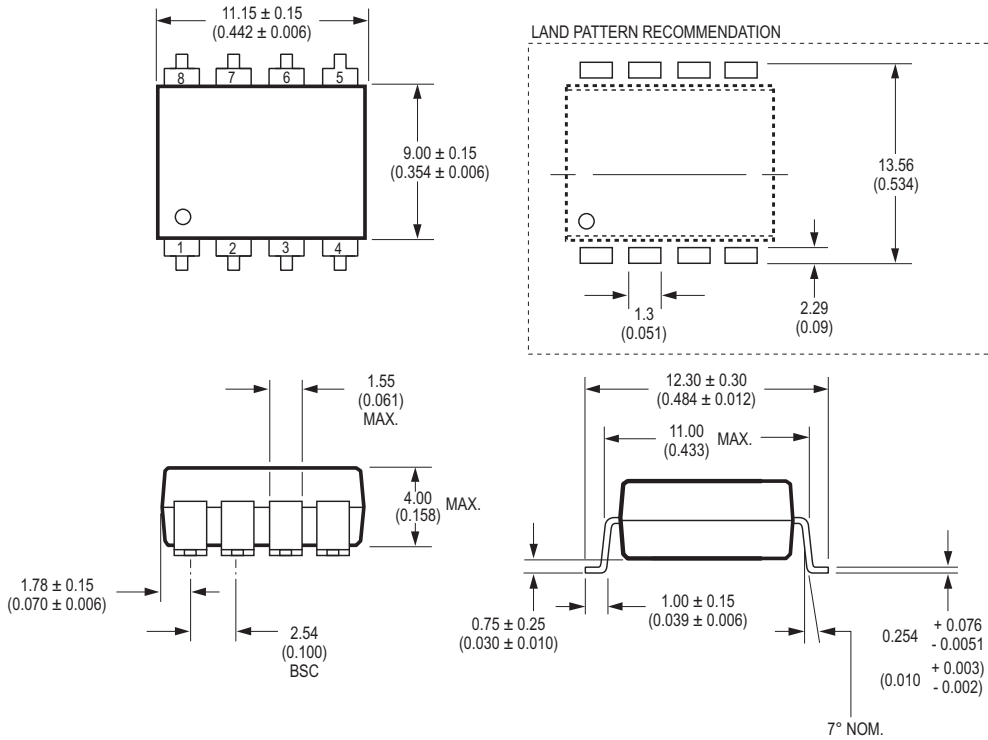
Option datasheets are available. Contact your Avago sales representative or authorized distributor for information.

Package Outline Drawings

ACNW3190 Outline Drawing (8-pin Wide Body Package)



ACNW3190 Gull Wing Surface Mount Option 300 Outline Drawing



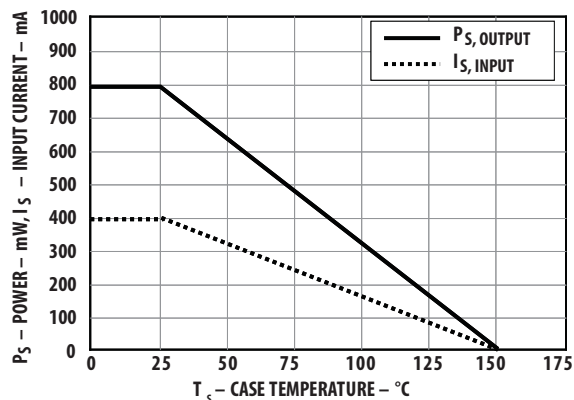
Dimensions in inches (millimeters)

Note:
Floating Lead Protrusion is 0.25 mm (10 mils) max.

Recommended Pb-Free IR Profile

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision). Non-Halide Flux should be used.

Dependence of Safety Limiting Values on Temperature



Note:

The Thermal Derating Graph above is in relation to Figure 30 and Figure 31 and $S = 2\text{cm}$.

Regulatory Information

The ACNW3190 is approved by the following organizations:

IEC/EN/DIN EN 60747-5-5

Maximum Working Insulation Voltage $V_{IORM} = 1414V_{PEAK}$

UL

Approval under UL 1577, component recognition program up to $V_{ISO} = 5000 V_{RMS}$ expected prior to product release. File E55361.

CSA

Approval under CSA Component Acceptance Notice #5, File CA 88324 expected prior to product release.

Table 1. IEC/EN/DIN EN 60747-5-5 Insulation Characteristics*

| Description | Symbol | Characteristic | Unit |
|--|-----------------|----------------|------------|
| Installation classification per DIN VDE 0110/1.89, Table 1 | | | |
| for rated mains voltage $\leq 150 V_{rms}$ | | I – IV | |
| for rated mains voltage $\leq 300 V_{rms}$ | | I – IV | |
| for rated mains voltage $\leq 450 V_{rms}$ | | I – IV | |
| for rated mains voltage $\leq 600 V_{rms}$ | | I – IV | |
| for rated mains voltage $\leq 1000 V_{rms}$ | | I – III | |
| Climatic Classification | | 55/100/21 | |
| Pollution Degree (DIN VDE 0110/1.89) | | 2 | |
| Maximum Working Insulation Voltage | V_{IORM} | 1414 | V_{peak} |
| Input to Output Test Voltage, Method b** | | | |
| $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ sec, Partial discharge < 5 pC | V_{PR} | 2652 | V_{peak} |
| Input to Output Test Voltage, Method a** | | | |
| $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test, $t_m = 10$ sec, Partial discharge < 5 pC | V_{PR} | 2262 | V_{peak} |
| Highest Allowable Overvoltage (Transient Overvoltage $t_{ini} = 60$ sec) | V_{IOTM} | 8000 | V_{peak} |
| Safety-limiting values | | | |
| – maximum values allowed in the event of a failure, also see Figure 2. | | | |
| Case Temperature | T_s | 150 | °C |
| Input Current | $I_{S, INPUT}$ | 400 | mA |
| Output Power | $P_{S, OUTPUT}$ | 800 | mW |
| Insulation Resistance at $T_s, V_{IO} = 500$ V | R_S | $\geq 10^9$ | Ω |

* Isolation characteristics are guaranteed only within the safety maximum ratings which must be ensured by protective circuits in application. Surface mount classification is class A in accordance with CECC00802.

** Refer to the optocoupler section of the Isolation and Control Components Designer's Catalog, under Product Safety Regulations section IEC/EN/DIN EN 60747-5-5, for a detailed description of Method a and Method b partial discharge test profiles.

Table 2. Insulation and Safety Related Specifications

| Parameter | Symbol | ACNW3190 | Units | Conditions |
|---|--------|----------|-------|--|
| Minimum External Air Gap (Clearance) | L(101) | 9.6 | mm | Measured from input terminals to output terminals, shortest distance through air. |
| Minimum External Tracking (Creepage) | L(102) | 10.0 | mm | Measured from input terminals to output terminals, shortest distance path along body. |
| Minimum Internal Plastic Gap (Internal Clearance) | | 1.0 | mm | Through insulation distance conductor to conductor, usually the straight line distance thickness between the emitter and detector. |
| Tracking Resistance (Comparative Tracking Index) | CTI | >200 | V | DIN IEC 112/VDE 0303 Part 1 |
| Isolation Group | | IIIa | | Material Group (DIN VDE 0110, 1/89, Table 1) |

Notes:

All Avago data sheets report the creepage and clearance inherent to the optocoupler component itself. These dimensions are needed as a starting point for the equipment designer when determining the circuit insulation requirements. However, once mounted on a printed circuit board, minimum creepage and clearance requirements must be met as specified for individual equipment standards. For creepage, the shortest distance path along the surface of a printed circuit board between the solder fillets of the input and output leads must be considered (the recommended Land Pattern does not necessarily meet the minimum creepage of the device). There are recommended techniques such as grooves and ribs which may be used on a printed circuit board to achieve desired creepage and clearances. Creepage and clearance distances will also change depending on factors such as pollution degree and insulation level.

Table 3. Absolute Maximum Ratings

| Parameter | Symbol | Min. | Max. | Units | Note |
|---|-------------------------|------|----------|-------|------|
| Storage Temperature | T_S | -55 | 125 | °C | |
| Operating Temperature | T_A | -40 | 100 | °C | |
| Output IC Junction Temperature | T_J | | 150 | °C | |
| Average Input Current | $I_{F(AVG)}$ | | 25 | mA | 1 |
| Peak Transient Input Current (<1 μ s pulse width, 300pps) | $I_{F(TRAN)}$ | | 1.0 | A | |
| Reverse Input Voltage | V_R | | 5 | V | |
| "High" Peak Output Current | $I_{OH(PEAK)}$ | | 5.0 | A | 2 |
| "Low" Peak Output Current | $I_{OL(PEAK)}$ | | 5.0 | A | 2 |
| Total Output Supply Voltage | $(V_{CC} - V_{EE})$ | -0.5 | 35 | V | |
| Input Current (Rise/Fall Time) | $t_{r(IN)} / t_{f(IN)}$ | | 500 | ns | |
| Output Voltage | $V_{O(PEAK)}$ | -0.5 | V_{CC} | V | |
| Output IC Power Dissipation | P_O | | 800 | mW | 3 |
| Total Power Dissipation | P_T | | 850 | mW | 4 |

Table 4. Recommended Operating Conditions

| Parameter | Symbol | Min. | Max. | Units | Note |
|-----------------------|---------------------|------|------|-------|------|
| Operating Temperature | T_A | -40 | 100 | °C | |
| Output Supply Voltage | $(V_{CC} - V_{EE})$ | 15 | 30 | V | |
| Input Current (ON) | $I_{F(ON)}$ | 10 | 16 | mA | |
| Input Voltage (OFF) | $V_{F(OFF)}$ | -3.6 | 0.8 | V | |

Table 5. Electrical Specifications (DC)

Unless otherwise noted, all typical values are at $T_A = 25^\circ\text{C}$, $V_{CC} - V_{EE} = 30\text{ V}$, $V_{EE} = \text{Ground}$; all Minimum/Maximum specifications are at Recommended Operating Conditions ($T_A = -40$ to 100°C , $I_{F(ON)} = 10$ to 16 mA , $V_{F(OFF)} = -3.6$ to 0.8 V , $V_{CC} = 15$ to 30 V , $V_{EE} = \text{Ground}$)

| Parameter | Symbol | Min. | Typ. | Max. | Units | Test Conditions | Fig. | Note |
|---|-------------------------|------------|------------|------|----------------------|--|-----------|------|
| High Level Output Current | I_{OH} | 1.0 | 2.75 | | A | $V_O = V_{CC} - 4$ | 2, 3, 17 | 5 |
| | | 4.0 | | | A | $V_O = V_{CC} - 15$ | | 2 |
| Low Level Output Current | I_{OL} | 1.0 | 3.5 | | A | $V_O = V_{EE} + 2.5$ | 5, 6, 18 | 5 |
| | | 4.0 | | | A | $V_O = V_{EE} + 15$ | | 2 |
| High Level Output Voltage | V_{OH} | $V_{CC}-4$ | $V_{CC}-3$ | | V | $I_O = -100\text{ mA}$ | 1, 3, 19 | 6, 7 |
| Low Level Output Voltage | V_{OL} | | 0.1 | 0.5 | V | $I_O = 100\text{ mA}$ | 4, 6, 20 | |
| High Level Supply Current | I_{CCH} | | 3.0 | 5.0 | mA | Output open, $I_F = 7$ to 16 mA | 7, 8 | |
| Low Level Supply Current | I_{CCL} | | 3.0 | 5.0 | mA | Output open, $V_F = -3.0$ to $+0.8\text{ V}$ | | |
| Threshold Input Current Low to High | I_{FLH} | | 3.5 | 8.0 | mA | $I_O = 0\text{ mA}$, $V_O > 5\text{ V}$ | 9, 15, 21 | |
| Threshold Input Voltage High to Low | V_{FHL} | 0.8 | | | V | | | |
| Input Forward Voltage | V_F | 1.2 | 1.6 | 1.95 | V | $I_F = 10\text{ mA}$ | 16 | |
| Temperature Coefficient of Input Forward Voltage | $\Delta V_F/\Delta T_A$ | | -1.3 | | mV/ $^\circ\text{C}$ | | | |
| Input Reverse Breakdown Voltage | BV_R | 5 | | | V | $I_R = 100\text{ }\mu\text{A}$ | | |
| Input Capacitance | C_{IN} | | 75 | | pF | $f = 1\text{ MHz}$, $V_F = 0\text{ V}$ | | |
| UVLO Threshold | V_{UVLO+} | 11.0 | 12.3 | 13.5 | V | $V_O > 5\text{ V}$, $I_F = 10\text{ mA}$ | 22, 28 | |
| | V_{UVLO-} | 9.5 | 10.7 | 12.0 | | | | |
| UVLO Hysteresis | $UVLO_{HYS}$ | | 1.6 | | | | | |

Table 6. Switching Specifications (AC)

Unless otherwise noted, all typical values are at $T_A = 25^\circ\text{C}$, $V_{CC} - V_{EE} = 30\text{ V}$, $V_{EE} = \text{Ground}$; all Minimum/Maximum specifications are at Recommended Operating Conditions ($T_A = -40$ to 100°C , $I_{F(ON)} = 10$ to 16 mA , $V_{F(OFF)} = -3.6$ to 0.8 V , $V_{CC} = 15$ to 30 V , $V_{EE} = \text{Ground}$).

| Parameter | Symbol | Min. | Typ. | Max. | Units | Test Conditions | Fig. | Note |
|---|--------------------------------|------|------|------|-------------------|--|------------------------------|--------|
| Propagation Delay Time to High Output Level | t_{PLH} | 0.10 | 0.30 | 0.50 | μs | $R_g = 10\text{ }\Omega$, $C_g = 10\text{ nF}$, $f = 10\text{ kHz}$, Duty Cycle = 50%, $I_F = 10\text{ mA}$, $V_{CC} = 30\text{ V}$ | 10, 11, 12, 14 13, 14, 23 | |
| Propagation Delay Time to Low Output Level | t_{PHL} | 0.10 | 0.30 | 0.50 | μs | | | |
| Pulse Width Distortion | PWD | | | 0.30 | μs | | | 15 |
| Propagation Delay Difference Between Any Two Parts | PDD ($t_{PHL} - t_{PLH}$) | | 0.35 | | μs | | 35, 36 | 10 |
| Rise Time | t_r | | 0.1 | | μs | | 23 | |
| Fall Time | t_f | | 0.1 | | μs | | | |
| UVLO to Turn On Delay | $t_{UVLO,ON}$ | | 0.8 | | μs | $V_O > 5\text{ V}$, $I_F = 10\text{ mA}$ | 22 | |
| UVLO to Turn Off Delay | $t_{UVLO,OFF}$ | | 0.6 | | μs | $V_O < 5\text{ V}$, $I_F = 10\text{ mA}$ | | |
| Output High Level Common Mode Transient Immunity | $ CM_H $ | 15 | 30 | | kV/ μs | $T_A = 25^\circ\text{C}$, $I_F = 10$ to 16 mA , $V_{CM} = 1500\text{ V}$, $V_{CC} = 30\text{ V}$ | 24 | 11, 12 |
| Output Low Level Common Mode Transient Immunity | $ CM_L $ | 15 | 30 | | kV/ μs | $T_A = 25^\circ\text{C}$, $V_F = 0\text{ V}$, $V_{CM} = 1500\text{ V}$, $V_{CC} = 30\text{ V}$ | | 11, 13 |

Table 7. Package Characteristics

Unless otherwise noted, all typical values are at $T_A = 25^\circ\text{C}$; all Minimum/Maximum specifications are at Recommended Operating Conditions.

| Parameter | Symbol | Min. | Typ. | Max. | Units | Test Conditions | Fig. | Note |
|---|---------------|-----------|---------------------------|------|--------------------|---|------------|------|
| Input-Output Momentary Withstand Voltage* | V_{ISO} | 5000 | | | V_{RMS} | $RH < 50\%$, $t = 1 \text{ min.}, T_A = 25^\circ\text{C}$ | | 8, 9 |
| Input-Output Resistance | R_{I-O} | 10^{12} | 10^{13} | | Ω | $V_{I-O} = 500 V_{DC}$, $T_A = 25^\circ\text{C}$ | | 9 |
| | | 10^{11} | | | | $V_{I-O} = 500 V_{DC}$, $T_A = 100^\circ\text{C}$ | | |
| Input-Output Capacitance | C_{I-O} | | 0.5 | 0.6 | pF | $f = 1 \text{ MHz}$ | | |
| LED-to-Ambient Thermal Resistance | θ_{LA} | | | | $^\circ\text{C/W}$ | | 29, 30, 31 | |
| LED-to-Detector Thermal Resistance | θ_{LD} | | See Thermal Model Section | | | See Thermal Model in Application Notes Section | | |
| Detector-to-Ambient Thermal Resistance | θ_{DA} | | | | | | | |

* The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating, refer to your equipment level safety specification or Avago Technologies Application Note 1074 entitled "Optocoupler Input-Output Endurance Voltage."

Notes:

- Derate linearly above 70°C free-air temperature at a rate of $0.3 \text{ mA}/^\circ\text{C}$.
- Maximum pulse width = $10 \mu\text{s}$. This value is intended to allow for component tolerances for designs with I_O peak minimum = 4.0 A . See Applications section for additional details on limiting I_{OH} peak.
- Derate linearly above 70°C free-air temperature at a rate of $4.8 \text{ mA}/^\circ\text{C}$.
- Derate linearly above 70°C free-air temperature at a rate of $5.4 \text{ mA}/^\circ\text{C}$.
- Maximum pulse width = $50 \mu\text{s}$.
- In this test V_{OH} is measured with a dc load current. When driving capacitive loads V_{OH} will approach V_{CC} as I_{OH} approaches zero amps.
- Maximum pulse width = 1 ms .
- In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage $\geq 6000 \text{ Vrms}$ for 1 second (leakage detection current limit, $I_{I-O} \leq 5 \mu\text{A}$).
- Device considered a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.
- The difference between t_{PHL} and t_{PLH} between any two ACNW3190 parts under the same test condition.
- Pins 1 and 4 need to be connected to LED common.
- Common mode transient immunity in the high state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM} , to assure that the output will remain in the high state (i.e., $V_O > 15.0 \text{ V}$).
- Common mode transient immunity in a low state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM} , to assure that the output will remain in a low state (i.e., $V_O < 1.0 \text{ V}$).
- This load condition approximates the gate load of a $1200 \text{ V}/100\text{A}$ IGBT.
- Pulse Width Distortion (PWD) is defined as $|t_{PHL} - t_{PLH}|$ for any given device.

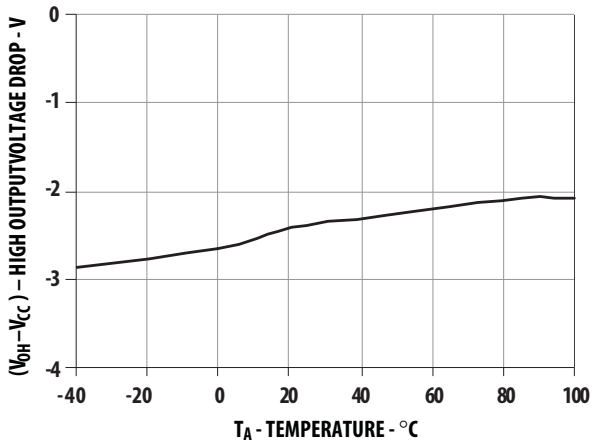


Figure 1. V_{OH} vs. Temperature

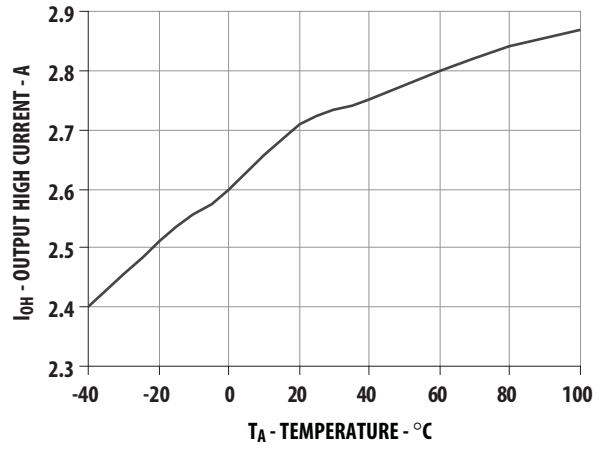


Figure 2. I_{OH} vs. Temperature

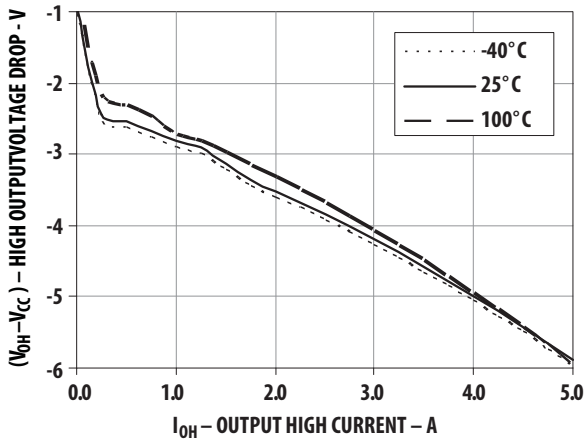


Figure 3. V_{OH} vs. I_{OH}

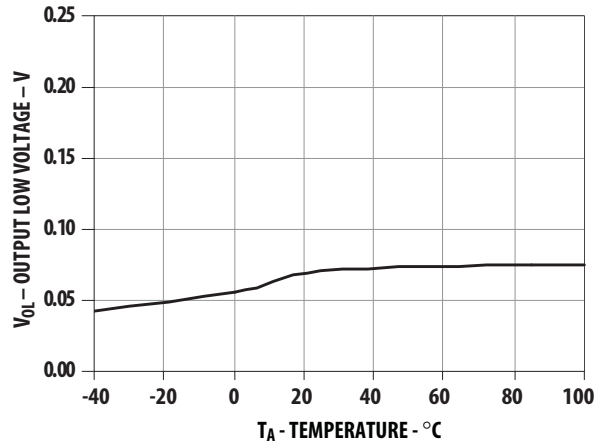


Figure 4. V_{OL} vs. Temperature

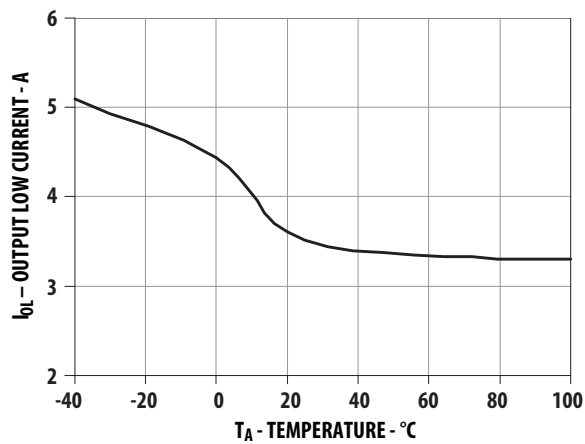


Figure 5. I_{OL} vs. Temperature

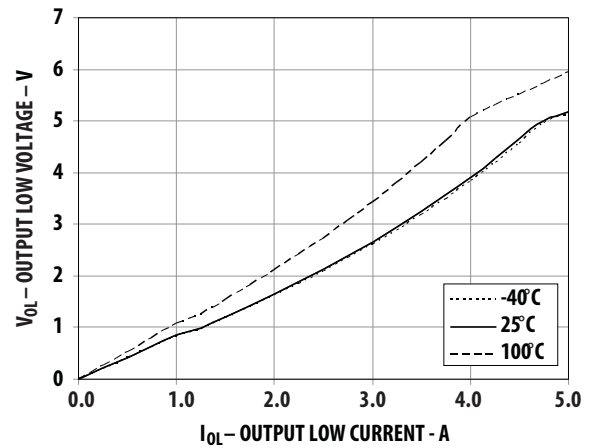


Figure 6. V_{OL} vs. I_{OL}

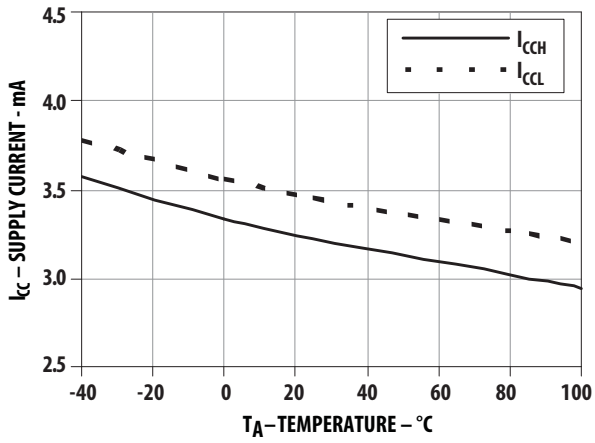


Figure 7. I_{CC} vs. Temperature

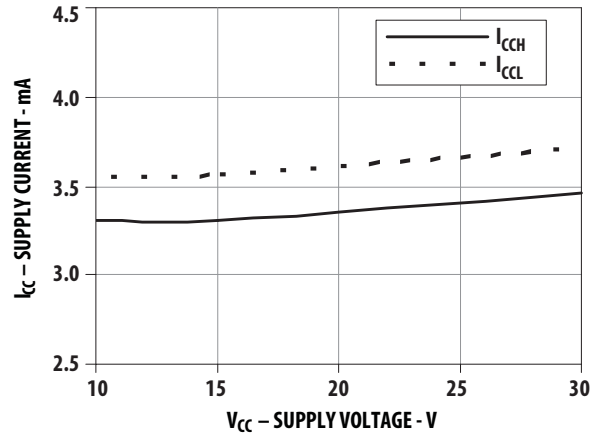


Figure 8. I_{CC} vs. V_{CC}

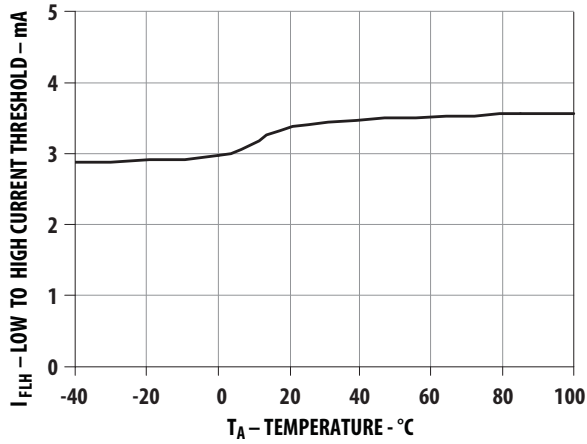


Figure 9. I_{FLH} vs. Temperature

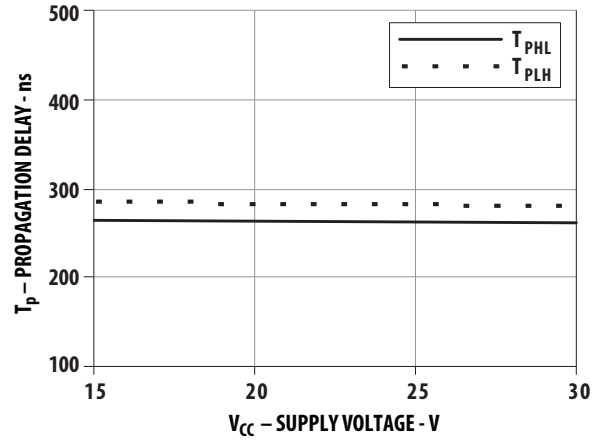


Figure 10. Propagation delay vs. V_{CC}

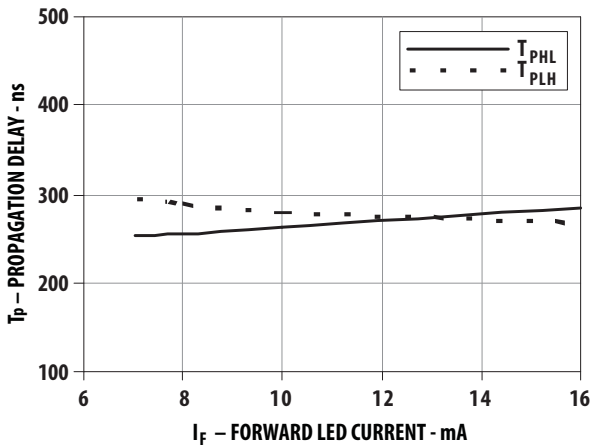


Figure 11. Propagation delay vs. I_F

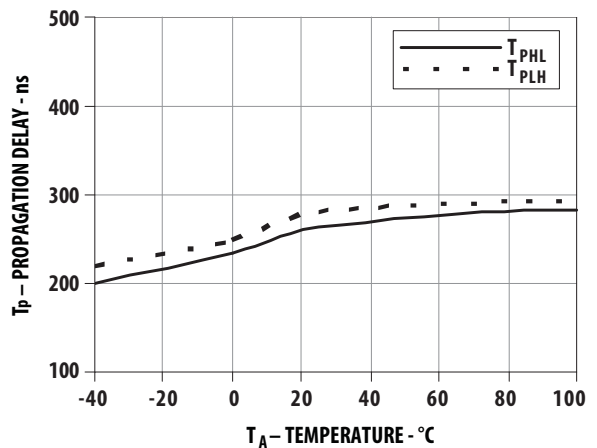


Figure 12. Propagation delay vs. Temperature

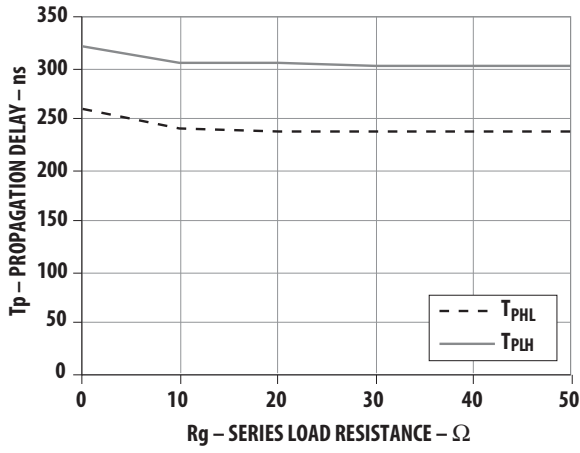


Figure 13. Propagation Delay vs. Rg

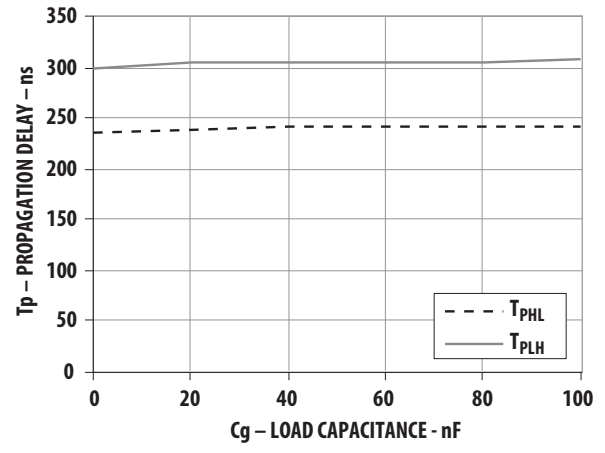


Figure 14. Propagation Delay vs. Cg

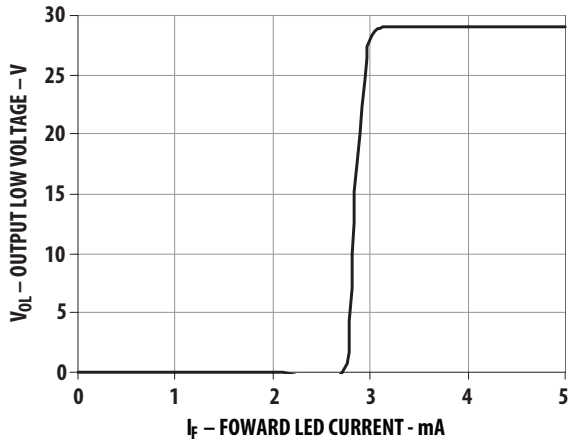


Figure 15. Transfer Characteristics

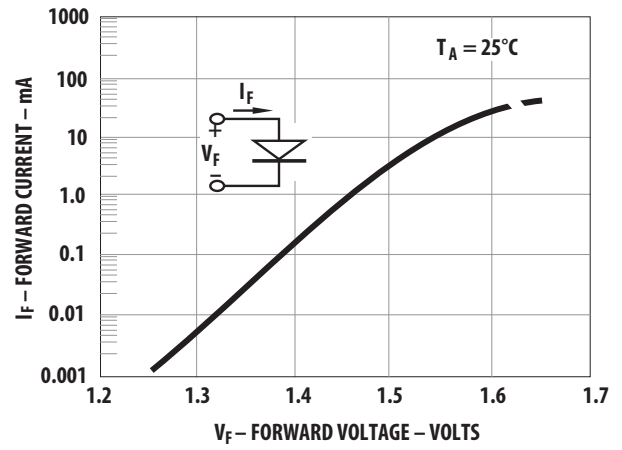


Figure 16. Input Current vs. Forward Voltage

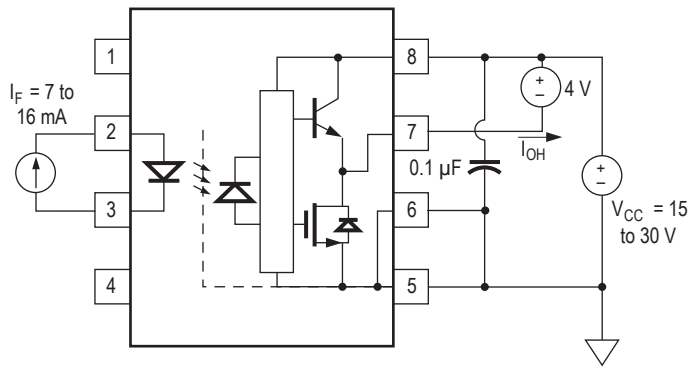


Figure 17. I_{OH} Test Circuit

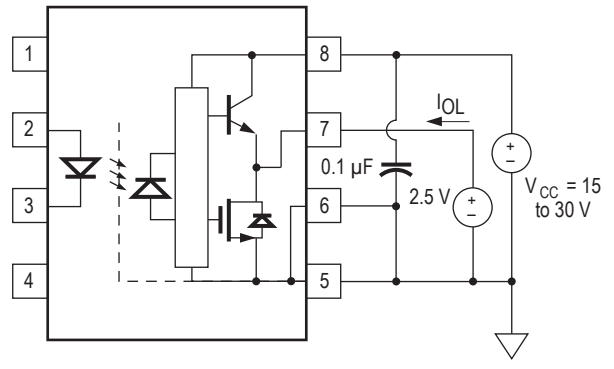


Figure 18. I_{OL} Test Circuit

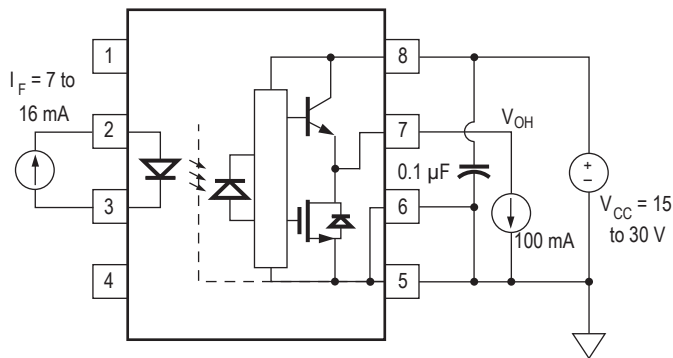


Figure 19. V_{OH} Test Circuit

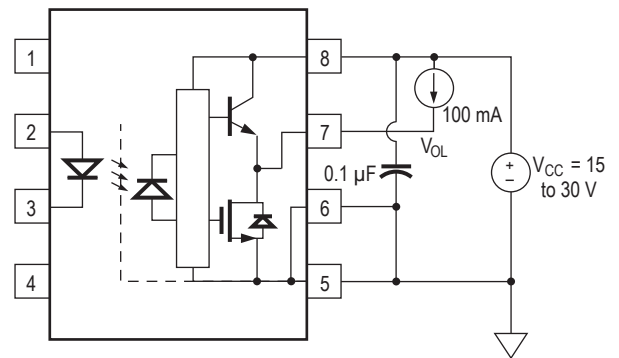


Figure 20. V_{OL} Test Circuit

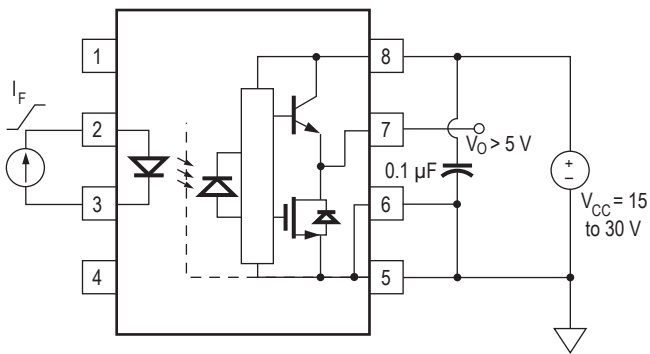


Figure 21. I_{FLH} Test Circuit

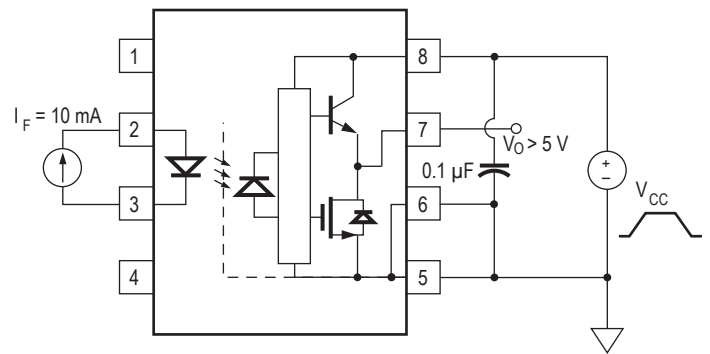


Figure 22. UVLO Test Circuit

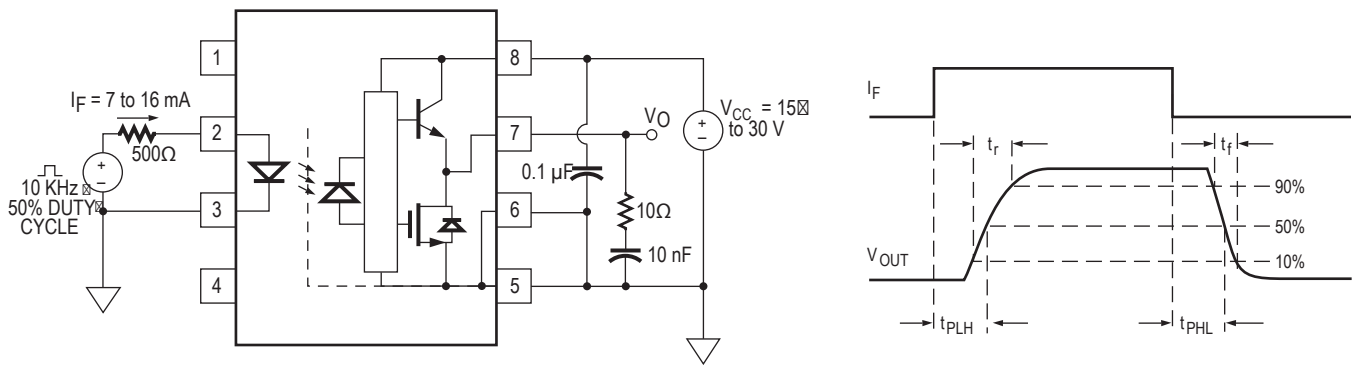


Figure 23. t_{PLH} , t_{PHL} , t_r , and t_f Test Circuit and Waveforms

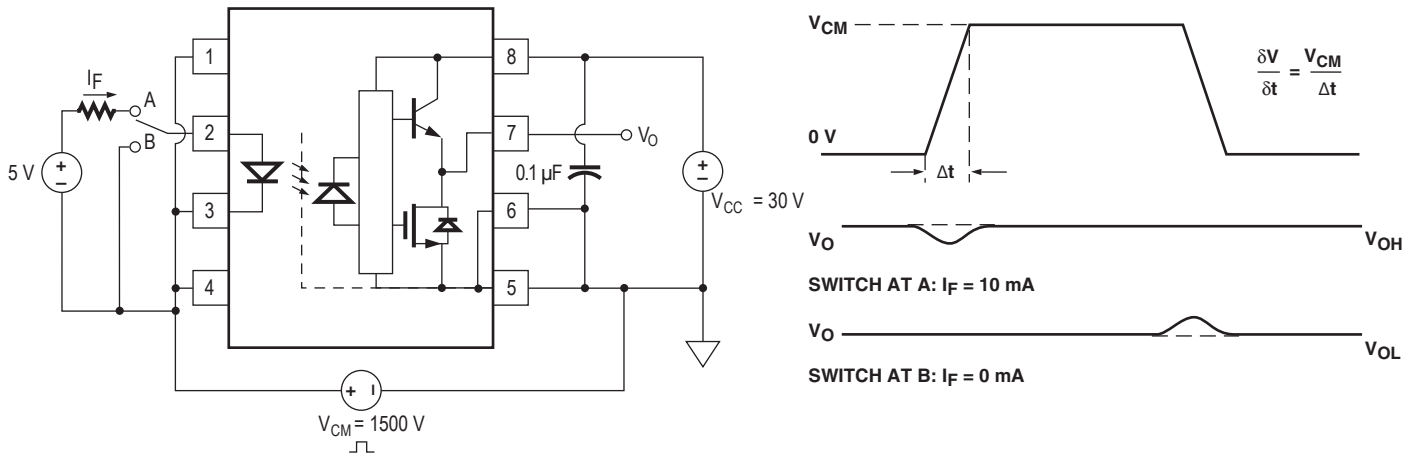


Figure 24. CMR Test Circuit and Waveforms

Application Notes

Figure 25 and 26 show two recommended application circuits. Figure 25 shows a single power supply gate driver using the driver's maximum V_{OL} value of 0.5V. Figure 26 shows a dual power supply gate driver circuit which is applicable for higher power IGBT driving due to the existence of higher miller capacitance in these IGBTs.

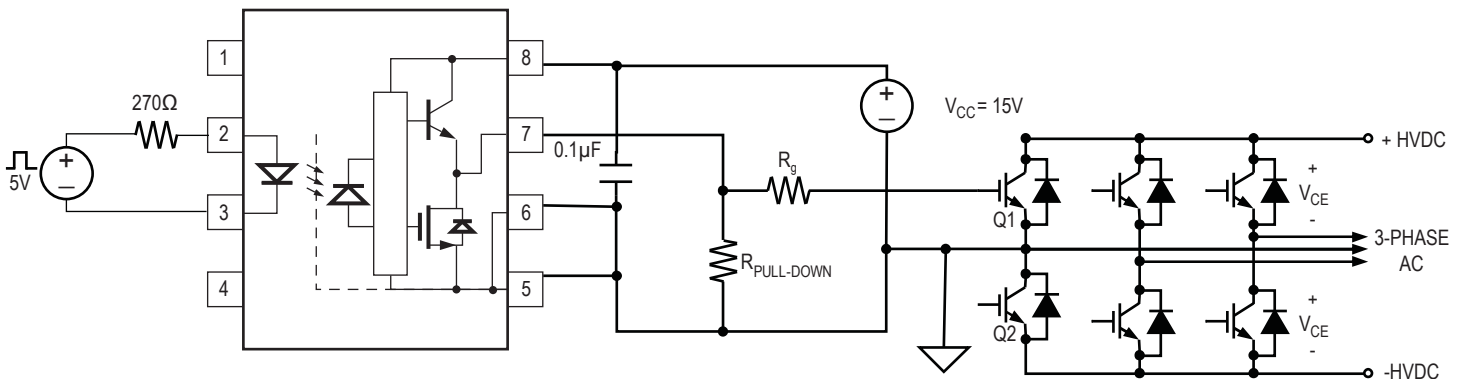


Figure 25. Recommended LED drive and application circuit

For high side bootstrap driving, note that the bypass capacitor of 0.1 μF in parallel with 10 μF or above to be connected across VCC and VEE is important to deliver high peak output current.

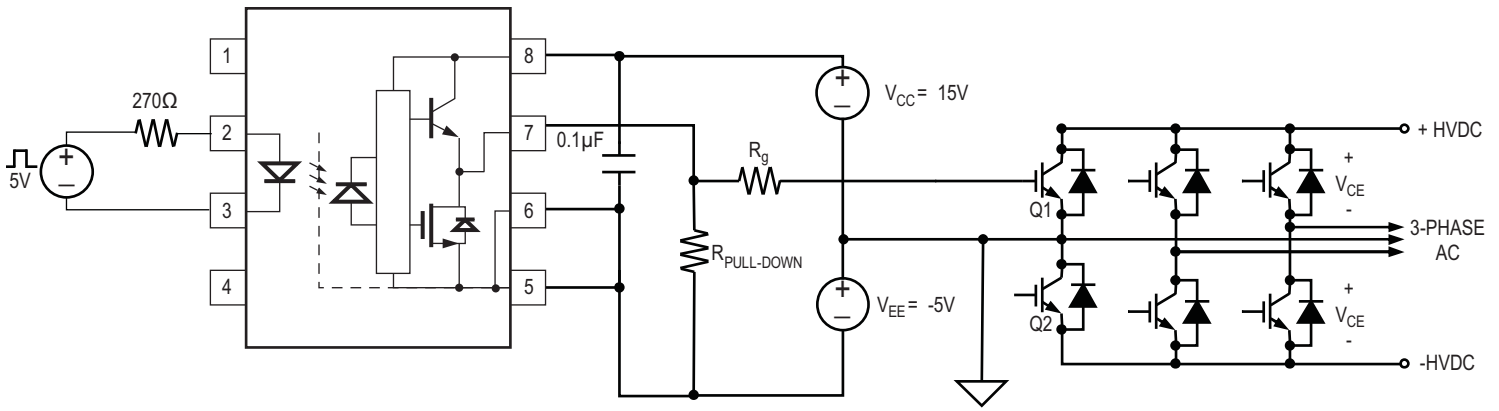


Figure 26. ACNW3190 typical application circuit with negative IGBT gate drive

Selecting the Gate Resistor (Rg) to minimize IGBT Switching Losses.

Step 1: Calculate Rg Minimum from the IOL Peak Specification

The IGBT and Rg in Figure 26 can be analyzed as a simple RC circuit with a voltage supplied by the ACNW3190. The operating temperature is 100°C.

$$R_g \geq \frac{(V_{CC} - V_{EE} - V_{OL})}{I_{OLPEAK}}$$

$$= \frac{(15V + 5V - 3.5V)}{4A}$$

$$\approx 4.3\Omega$$

The VOL value of 3.5V in the previous equation is a conservative value of VOL at the peak current of 4.0A (see Figure 6). At lower Rg values the voltage supplied by the ACNW3190 is not an ideal voltage step. This results in lower peak currents (more margin) than predicted by this analysis. When negative gate drive is not used, VEE in the previous equation is equal to zero volts.

Step 2: Check the ACNW3190 Power Dissipation and Increase Rg if Necessary.

The ACNW3190 total power dissipation (PT) is equal to the sum of the emitter power (PE) and the output power (PO):

$$P_T = P_E + P_O$$

$$P_E = I_F * V_F * \text{Duty Cycle}$$

$$P_O = P_{O(BIAS)} + P_{O(SWITCHING)}$$

$$= I_{CC} * (V_{CC} - V_{EE}) + E_{SW}(R_g, Q_g) * f$$

For the circuit in Figure 26 with IF (worst case) = 16 mA, Rg = 4.3Ω, Max Duty Cycle = 80%, Qg = 1000 nC, f = 15 kHz and TA max = 85°C:

$$P_E = 16 \text{ mA} * 1.95V * 0.8 = 25 \text{ mW}$$

$$P_O = 3.25 \text{ mA} * 20 \text{ V} + 13\mu\text{J} * 15 \text{ kHz}$$

$$= 65 \text{ mW} + 195 \text{ mW}$$

$$= 260 \text{ mW}$$

$$< 728 \text{ mW} (P_{O(MAX)} @ 85^\circ\text{C} = 800 \text{ mW} - 15\text{C} * 4.8 \text{ mW/C})$$

The value of 3.25 mA for ICC in the previous equation was obtained by derating the ICC max of 5 mA to ICC max at 100C (see Figure 7).

The above computation shows that the power dissipation is within the specified limits. However, designers should verify that the thermal limits have not been violated by using the thermal model provided in this datasheet. This thermal model obtained based on JEDEC specification.

| PE Parameter | Description |
|--------------|------------------------|
| IF | LED Current |
| VF | LED On Voltage |
| Duty Cycle | Maximum LED Duty Cycle |

| P0 Parameter | Description |
|--------------|--|
| ICC | Supply Current |
| VCC | Positive Supply Voltage |
| VEE | Negative Supply Voltage |
| ESW(Rg,Qg) | Energy Dissipated in the HCPL-3120 for each IGBT Switching Cycle (See Figure 27) |
| f | Switching Frequency |

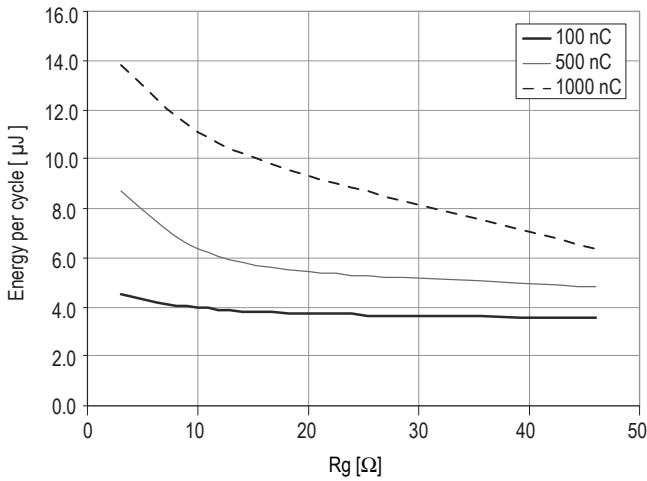


Figure 27. Energy dissipated in the ACNW3190 for each IGBT switching cycle

Under Voltage Lockout Feature

The ACNW3190 contains an under voltage lockout (UVLO) feature that is designed to protect the IGBT under fault conditions which cause the ACNW3190 supply voltage (equivalent to the fully-charged IGBT gate voltage) to drop below a level necessary to keep the IGBT in a low resistance state. When the ACNW3190 output is in the high state and the supply voltage drops below the ACNW3190 V_{UVLO-} threshold ($9.5 < V_{UVLO-} < 12.0$) the optocoupler output will go into the low state with a typical delay, UVLO Turn Off Delay, of 0.6 μ s. When the ACNW3190 output is in the low state and the supply voltage rises above the ACNW3190 V_{UVLO+} threshold ($11.0 < V_{UVLO+} < 13.5$) the optocoupler output will go into the high state (assumes LED is "ON") with a typical delay, UVLO Turn On Delay of 0.8 μ s.

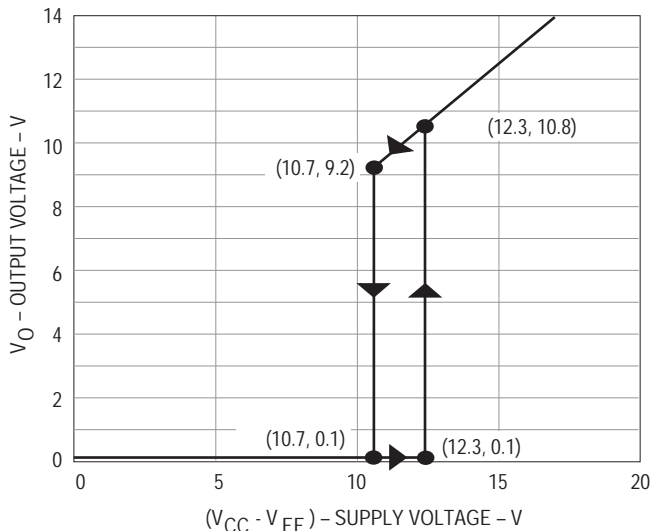


Figure 28. Under Voltage Lock Out

Thermal Model

Introduction

For application which requires an output gate current more than 2A, adequate PCB pad heat-sink must be provided to dissipate the power loss in the package. Failure to provide proper heat dissipation will potentially damage the gate drive after pro-long usage. This thermal model allows designer to compute the temperature of the LED and detector.

Definitions

θ_1 : Thermal impedance from LED junction to ambient

θ_2 : Thermal impedance from LED to detector (output IC)

θ_3 : Thermal impedance from detector (output IC) junction to ambient

Ambient Temperature: Measured approximately 1.25 cm above the optocoupler, with no forced air.

Description

This thermal model assumes that an 8-pin single-channel plastic package optocoupler is soldered into a 7.62 cm x 7.62 cm printed circuit board (PCB). The temperature at the LED and Detector junctions of the optocoupler can be calculated using the equations below.

$$\Delta T_{EA} = A_{11} * P_E + A_{12} * P_D$$

$$\Delta T_{DA} = A_{21} * P_E + A_{22} * P_D$$

where,

ΔT_{EA} = Temperature difference between ambient and LED

ΔT_{DA} = Temperature difference between ambient and detector

P_E = Power dissipation from LED

P_D = Power dissipation from detector

A_{11} , A_{12} , A_{21} , A_{22} thermal coefficients (units in $^{\circ}\text{C}/\text{W}$) are functions of the thermal impedances θ_1 , θ_2 , θ_3 (See Note 2).

Table 1. Thermal Model-B Coefficient Data (units in $^{\circ}\text{C}/\text{W}$)

| S (cm) | A11 | A12, A21 | A22 |
|-----------------------------|-------|----------|-------|
| 1 | 218.9 | 39.31 | 55.3 |
| 2 | 200.6 | 29.8 | 45 |
| 4 | 198 | 23.59 | 41.7 |
| JeDEC Specifications | | | |
| low K board | 254 | 50.3 | 66.8 |
| High K board | 151.2 | 16.72 | 39.06 |

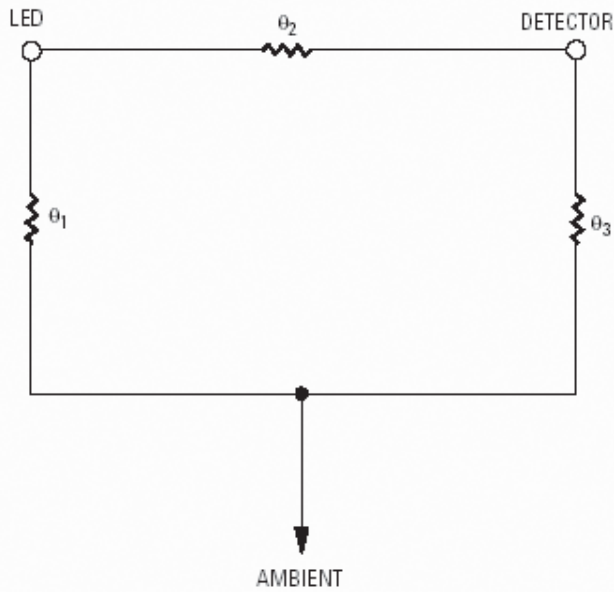


Figure 29. Thermal Model-B Diagram

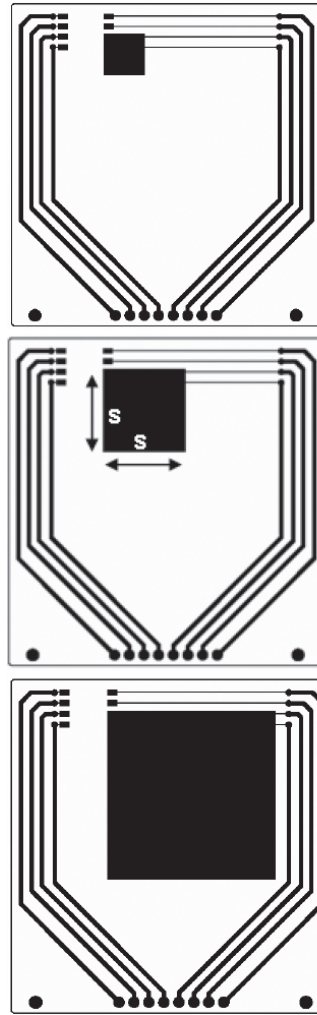


Figure 30. Evaluation thermal board design

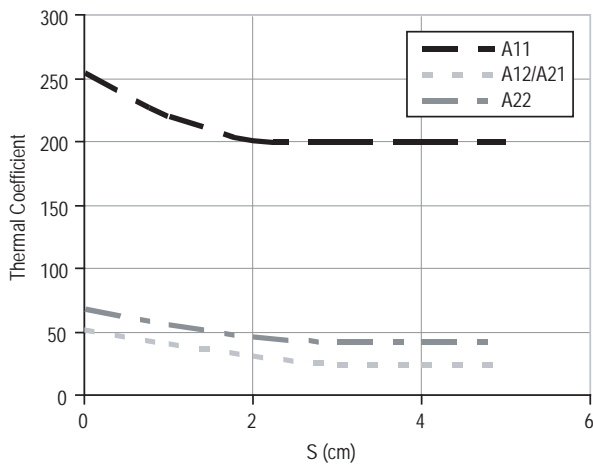


Figure 31. Thermal Coefficient Plot against S

Notes:

1. Maximum junction temperature for above parts: 150 °C.
2. $A11 = \theta_1 || (\theta_2 + \theta_3)$; $A12 = A21 = (\theta_1 \theta_2) / (\theta_1 + \theta_2 + \theta_3)$; $A22 = \theta_3 || (\theta_2 + \theta_3)$.

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